

10 / 525 244

DT01 Rec'd PCT/PTC 22 FEB 2005

**OLIFF & BERRIDGE, PLC**

ATTORNEYS AT LAW

**Application Data Sheet****Applicant Information**

Applicant Authority type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Ryoji
Family Name::	HOSHI
City of Residence::	Fukushima
Country of Residence::	Japan

---

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Susumu
Family Name::	SONOKAWA
City of Residence::	Fukushima
Country of Residence::	Japan

**Correspondence Information**

Correspondence Customer Number::	25944
----------------------------------	-------

**Application Information**

Application Type::	National Phase
Subject Matter::	Utility
CD-ROM or CD-R::	None
Title::	SINGLE CRYSTAL, SINGLE CRYSTAL WAFER, EPITAXIAL WAFER, AND METHOD OF GROWING SINGLE CRYSTAL
Attorney Docket Number::	122810
Total Drawing Sheets::	5
Small Entity::	No

**Representative Information**

James A. Oliff, Reg. No. 27,075  
Kirk M. Hudson, Reg. No. 27,562  
Edward P. Walker, Reg. No. 31,450  
Mario A. Costantino, Reg. No. 33,565

William P. Berridge, Reg. No. 30,024  
Thomas J. Pardini, Reg. No. 30,411  
Robert A. Miller, Reg. No. 32,771  
Stephen J. Roe, Reg. No. 34,463

<b>Domestic Priority Information</b>			
Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application is a	National Stage of	PCT/JP03/11443	09/08/03
<b>Foreign Priority Information</b>			
Country::	Application Number::	Filing Date::	Priority Claimed::
Japan	2002-267563	09/13/02	Yes
<b>Assignee Information</b>			
Assignee Name::		Shin-Etsu Handotai Co., Ltd.	
Street of mailing address::		4-2, Marunouchi 1-chome, Chiyoda-ku	
City of mailing address::		Tokyo	
Country of mailing address::		Japan	